





### **SL520A SCHOTTKY RECTIFIER**



#### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	200	٧
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>c</sub> =115°C, rectangular wave form	5	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	120	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 5A, Pulse, T <sub>J</sub> = 25 °C	0.82	0.89	V
	V <sub>F2</sub>	@ 5A, Pulse, T <sub>J</sub> = 125°C	0.68	0.76	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25℃	0.0002	0.1	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125°C	0.06	20	mA
Junction Capacitance	Cj	@V <sub>R</sub> = 5.0 V, Tc=25 ℃ f <sub>SIG</sub> = 1MHz	91	150	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	20	°C/W
Approximate Weight	wt	-	0.06	g

### **Ratings and Characteristics Curves**

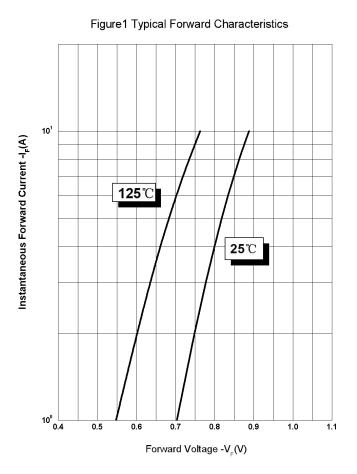


Figure 3 Typical Junction Capacitance

25°C

100

25°C

100

2 4 6 8 10

Reverse Voltage -V (V)

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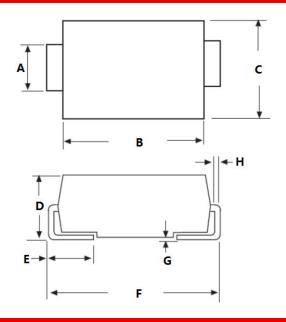
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### **Mechanical Dimensions SMA**



SYMBOL	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
А	1.25	1.65	0.049	0.065	
В	3.95	4.60	0.156	0.181	
С	2.25	2.95	0.089	0.116	
D	1.95	2.90	0.077	0.114	
E	0.75	1.60	0.030	0.063	
F	4.80	5.60	0.189	0.220	
G	0.05	0.20	0.002	0.008	
Н	0.15	0.41	0.006	0.016	

### **Ordering Information**

Device	Package	Shipping
SL520A	SMA (Pb-Free)	5000pcs / reel
SL520ATR	SMA (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**



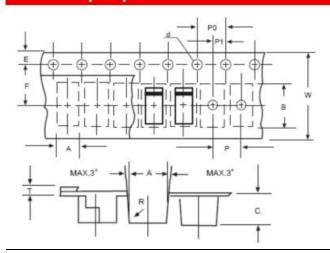
Where XXXXX is YYWWL

SL = Device Type 5 = Forward Current (5A) 20 = Reverse Voltage (200V) A = Package type

YY = Year WW = Week L = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

## **Carrier Tape Specification SMA**



SYMBOL	Millimeters		
STIVIBUL	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
Е	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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